**Product data sheet** 

# 1. General description

Ultrafast power diode bare die.

## 2. Features and benefits

- · Fast switching
- Low forward voltage drop
- · Soft recovery characteristic
- Bare die

## 3. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>RRM</sub> *	repetitive peak reverse voltage		-	-	600	V
I <sub>F(AV)</sub> **	average forward current	$\delta$ = 0.5 ; square-wave pulse	-	-	30	Α
Static characte	eristics					
V <sub>F</sub> **	forward voltage	I <sub>F</sub> = 5 A; T <sub>j</sub> = 25 °C	0.8	1.15	1.28	V
		I <sub>F</sub> = 30 A; T <sub>j</sub> = 25 °C	-	1.2	1.3	V
Dynamic chara	acteristics					·
t <sub>rr</sub> **	reverse recovery time	$I_F$ = 1A; $dI_F/dt$ = 50 A/µs; $V_R$ = 30 V; $T_j$ = 25 °C;	-	-	75	ns

# 4. Ordering information

Table 2. Ordering information

Type number	Package			
	Name	Description	Version	
WNB160V5SPTS	Wafer	Bare die on wafer	Die	

# 5. Limiting values

## **Table 2. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>RRM</sub> *	repetitive peak reverse voltage		-	600	V
V <sub>RWM</sub> *	crest working reverse voltage		-	600	V
$V_R^*$	reverse voltage	DC	-	600	V
I <sub>F(AV)</sub> **	average forward current	$\delta$ = 0.5 ; square-wave pulse	-	30	Α
I <sub>FRM</sub> **	repetitive peak forward current	$\delta$ = 0.5 ; $t_p$ = 25 $\mu$ s; square-wave pulse	-	60	Α
I <sub>FSM</sub> **	non-repetitive peak	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	-	320	Α
	forward current	$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; square-wave pulse	-	350	Α
T <sub>stg</sub> **	storage temperature		-55	175	°C
T <sub>j</sub> **	junction temperature		-	175	°C

### 6. Characteristics

#### **Table 3. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics				,	
V <sub>F</sub> **	forward voltage	I <sub>F</sub> = 5 A; T <sub>j</sub> = 25 °C	8.0	1.15	1.28	V
		I <sub>F</sub> = 30 A; T <sub>j</sub> = 25 °C	-	1.2	1.3	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C	-	-	10	μΑ
		V <sub>R</sub> = 600 V; T <sub>j</sub> = 125 °C	-	-	500	μΑ
Dynamic ch	naracteristics					
t <sub>rr</sub> **	reverse recovery time	$I_F$ = 1A; $dI_F/dt$ = 50 A/ $\mu$ s; $V_R$ = 30 V; $T_j$ = 25 °C;	-	-	75	ns

#### Notes:

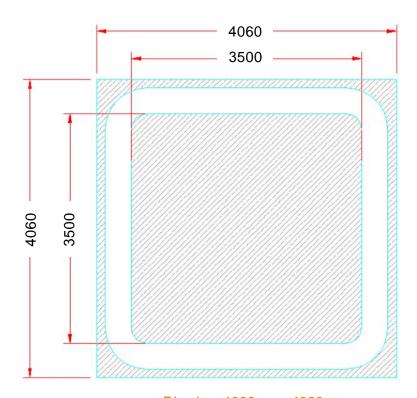
<sup>(1) \*</sup> mean that parameter are 100% test at  $T_{amb} = 25$  °C.

<sup>(2) \*\*</sup> means that the guaranteed ratings and parameter limits will depend on the assembled structure. When correctly assembled with suitable die bonding and wire bonding, the device will have ratings and characteristics guaranteed in this data sheet.

#### MECHANICAL PARAMETER

Chip size	4.06 x 4.06	mm²
Anode pad size	3.5 x 3.5	mm²
Area total /active	16.48 /12.25	mm²
Thickness	300	μm
Wafer size	125	mm
Max possible chips per wafer	658	pcs
Passivation	Glass	
Front metal	Al Ti Ni Ag	
Back metal	Ti Ni Ag	

### **CHIP LAYOUT**



Die size: 4060um x 4060um Bond pad size: 3500um x 3500um

# 7. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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# WNB160V5SPTS

Ultrafast power diode - Bare die

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For more information, please visit: http://www.ween-semi.com For sales office addresses, please send an email to: salesaddresses@weensemi.com Date of release: 3 April 2018

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